

MSA-0986

Cascadable Silicon Bipolar MMIC Amplifier

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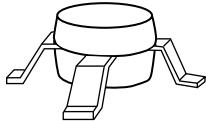
Data Sheet

Description

The MSA-0986 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount plastic package. This MMIC is designed for very wide bandwidth industrial and commercial applications that require flat gain and low VSWR.

The MSA-series is fabricated using Avago's 10 GHz f_T , 25 GHz f_{MAX} , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

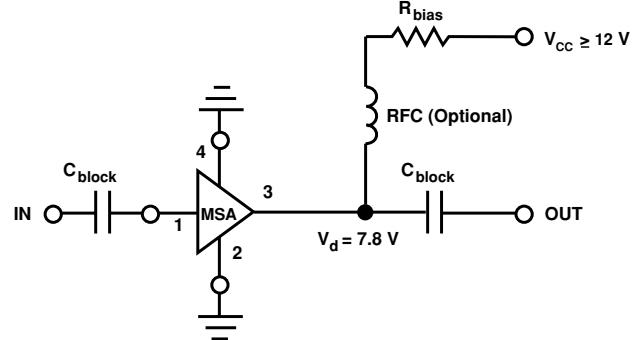
86 Plastic Package



Features

- Broadband, Minimum Ripple Cascadable 50Ω Gain Block
- 7.2 ± 0.5 dB Typical Gain Flatness from 0.1 to 3.0 GHz
- 3 dB Bandwidth: 0.1 to 5.5 GHz
- 10.5 dBm Typical P_{1dB} at 2.0 GHz
- Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available
- Lead-free Option Available

Typical Biasing Configuration



MSA-0986 Absolute Maximum Ratings

Parameter	Absolute Maximum ^[1]
Device Current	65 mA
Power Dissipation ^[2,3]	500 mW
RF Input Power	+13 dBm
Junction Temperature	150°C
Storage Temperature	-65 to +150°C

Thermal Resistance^[2]:

$$\theta_{jc} = 140^\circ\text{C/W}$$

Notes:

1. Permanent damage may occur if any of these limits are exceeded.
2. $T_{CASE} = 25^\circ\text{C}$.
3. Derate at 7.1 mW/°C for $T_C > 80^\circ\text{C}$.

Electrical Specifications^[1], $T_A = 25^\circ\text{C}$

Symbol	Parameters and Test Conditions: $I_d = 35 \text{ mA}$, $Z_0 = 50 \Omega$	Units	Min.	Typ.	Max.
G_P	Power Gain ($ S_{21} ^2$)	dB	6.0	7.2	
ΔG_P	Gain Flatness	dB		±0.5	
$f_3 \text{ dB}$	3 dB Bandwidth ^[2]	GHz		5.5	
VSWR	Input VSWR	f = 1.0 to 3.0 GHz		1.6:1	
	Output VSWR			1.8:1	
NF	50 Ω Noise Figure	f = 2.0 GHz	dB	6.2	
$P_{1 \text{ dB}}$	Output Power at 1 dB Gain Compression	f = 2.0 GHz	dBm	10.5	
IP ₃	Third Order Intercept Point	f = 2.0 GHz	dBm	23.0	
t_D	Group Delay	f = 2.0 GHz	psec	95	
V_d	Device Voltage	V	6.2	7.8	9.4
dV/dT	Device Voltage Temperature Coefficient	mV/°C		-16.0	

Notes:

1. The recommended operating current range for this device is 25 to 45 mA. Typical performance as a function of current is on the following page.
2. Referenced from 0.1 GHz gain (G_P).

Ordering Information

Part Numbers	No. of Devices	Comments
MSA-0986-BLK	100	Bulk
MSA-0986-BLKG	100	Bulk
MSA-0986-TR1	1000	7" Reel
MSA-0986-TR1G	1000	7" Reel
MSA-0986-TR2	4000	13" Reel
MSA-0986-TR2G	4000	13" Reel

Note: Order part number with a "G" suffix if lead-free option is desired.

MSA-0986 Typical Scattering Parameters ($Z_0 = 50 \Omega$, $T_A = 25^\circ\text{C}$, $I_d = 35 \text{ mA}$)

Freq. GHz	S ₁₁		S ₂₁			S ₁₂			S ₂₂		k
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	
0.02	.36	-105	11.4	3.72	145	-14.1	.198	18	.38	-102	0.73
0.05	.24	-145	8.5	2.65	156	-13.7	.205	5	.25	-143	1.08
0.1	.22	-164	7.7	2.43	166	-13.5	.211	4	.22	-158	1.17
0.2	.21	-179	7.5	2.37	167	-13.5	.212	1	.22	-172	1.20
0.4	.21	165	7.4	2.34	162	-13.4	.214	-1	.22	179	1.20
0.6	.22	155	7.4	2.33	156	-13.5	.212	-2	.22	175	1.21
0.8	.22	145	7.3	2.33	149	-13.4	.213	-2	.23	171	1.21
1.0	.23	136	7.3	2.32	142	-13.4	.214	-4	.24	167	1.20
1.5	.24	118	7.2	2.30	125	-13.3	.217	-6	.26	157	1.19
2.0	.25	106	7.2	2.28	109	-13.0	.224	-10	.28	148	1.16
2.5	.26	100	7.2	2.29	94	-13.0	.224	-12	.33	139	1.15
3.0	.26	94	7.1	2.26	77	-13.0	.224	-15	.34	128	1.15
3.5	.26	95	7.0	2.23	60	-12.8	.229	-21	.36	116	1.14
4.0	.28	96	6.7	2.17	43	-13.1	.221	-25	.35	104	1.18
4.5	.31	100	6.5	2.10	26	-13.6	.210	-31	.32	94	1.23
5.0	.37	101	6.0	2.00	9	-14.2	.196	-35	.26	86	1.30
5.5	.44	97	5.4	1.86	-7	-14.9	.181	-38	.19	88	1.38
6.0	.51	94	4.6	1.69	-22	-15.8	.162	-37	.14	107	1.47

Typical Performance, $T_A = 25^\circ\text{C}$

(unless otherwise noted)

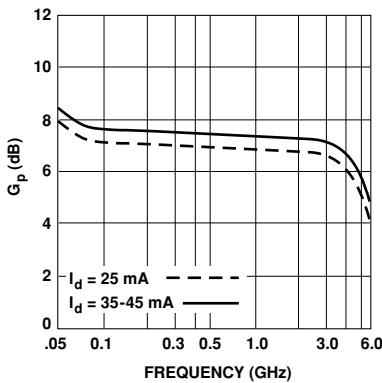


Figure 1. Typical Power Gain vs. Frequency.

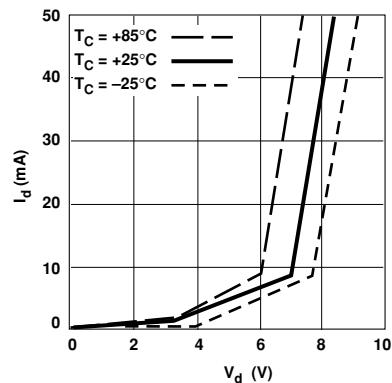


Figure 2. Device Current vs. Voltage.

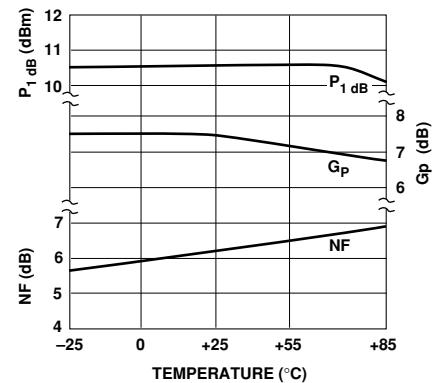


Figure 3. Output Power at 1 dB Gain Compression, Noise Figure and Power Gain vs. Case Temperature, $f = 2.0 \text{ GHz}$, $I_d = 35 \text{ mA}$.

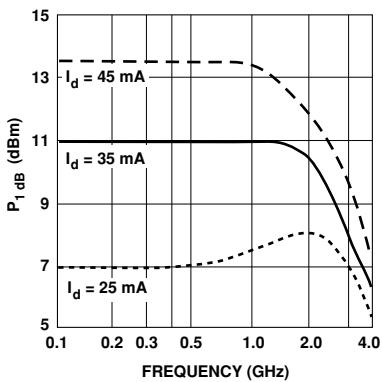


Figure 4. Output Power at 1 dB Gain Compression vs. Frequency.

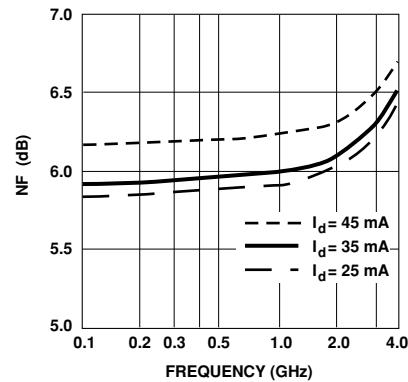
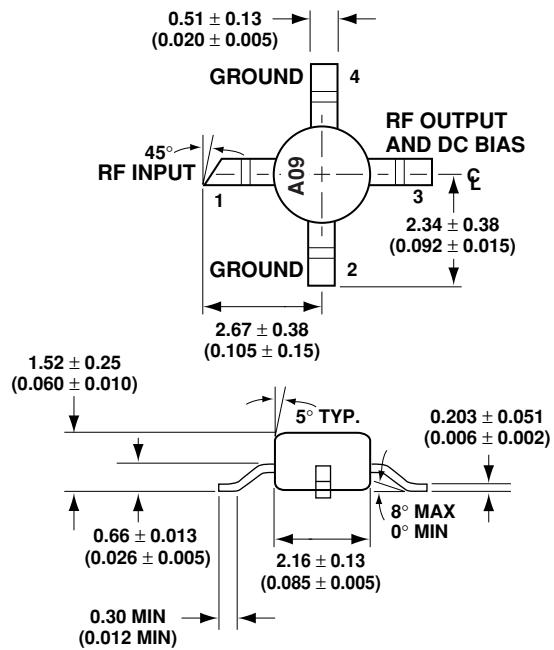


Figure 5. Noise Figure vs. Frequency.

86 Plastic Package Dimensions



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